## R13

## II B. Tech II Sem ester Supplementary Examinations, Nov/Dec-2016 **PULSE AND DIGITAL CIRCUITS** (Com. to EEE and ECC) Time: 3 hours Max. Marks: 70 Note: 1. Questi on Paper consists of two parts (**Part-A** and **Part-B**) 2. Answ er ALL the questions in Part-A 3. Answ er any THREE Questions from Part-B PART –A 1. a) Define rise time. (3M)b) Design a clamping circuit using diode to restore the positive peaks of 2 kHz signal (5M) to 3V. Assume $R_f = 100$ , $R_r = 200k$ , drop across diode is 0.6V. c) Discuss stable and qua si-stable states of a binary. Mention how many stable and (4M) quasi stable states are there in bitable, astable and constable multi vibr ators. d) Write the advantages of MOS families over bipolar families. (4M)e) What is the difference between a voltage time base generator and a current time (3M) base generator? Mentio n an application of time base generators. What is a relaxation device? Give few examples of them. f) (3M) PART-B

- 2. a) Using relevant diagram s and wave forms explain the response of a low pass RC (10M) circuit to sinusoidal inp ut. Obtain the expression for its output voltage.
  - b) Discuss in detail about diode reverse recovery time. (6M)
- 3. a) Obtain the transfer cha racteristic for the clipper circuit shown in figure below. (10M)



- b) Explain the operation of an emitter coupled clipper using relevant circ uit diagram. (6M)
- 4. Explain the operation of a Schmitt trigger circuit using relevant diagra m and (16M) derive the expression f or UTP and LTP.
- 5. a) Explain the operation of a 2 input NMOS NOR gate.(8M)b) Explain the operation of a CMOS inverter.(8M)
- 6. a) Explain the working of a UJT relaxation oscillator. (8M)
- b) Define and derive the relation between  $e_s$ ,  $e_t$  and  $e_d$ ? (8M)
- 7. a) Explain the operating p rinciple of a basic sampling gate. (8M)
  b) Explain frequency division in the sweep circuit. (8M)
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